



HIGH FREQUENCY HIGH-SIDE AND LOW-SIDE GATE DRIVER IN U-DFN3030-10

Description

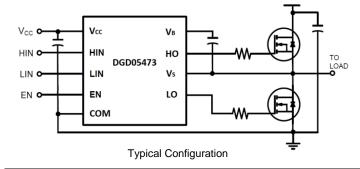
The DGD05473 is a high-frequency gate driver capable of driving N-channel MOSFETs. The floating high-side driver is rated up to 50V.

The DGD05473 logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with MCUs. UVLO for high-side and low-side protects a MOSFET with loss of supply. To protect MOSFETs, cross conduction prevention logic prevents the HO and LO outputs from being on at the same time.

Fast and well-matched propagation delays allow a higher switching frequency, enabling a smaller, more compact power switching design, using smaller associated components. To minimize space an internal bootstrap diode is included. The DGD05473 is offered in the U-DFN3030-10 package and operates over an extended -40°C to +125°C temperature range.

Applications

- DC-DC Converters
- Motor Controls
- Battery Powered Hand Tools
- eCig Devices
- Class D Power Amplifiers



Features

- 50V Floating High-Side Driver
- Drives Two N-Channel MOSFETs in a Half-Bridge Configuration
- 1.5A Source / 2.5A Sink Output Current Capability
- Internal Bootstrap Diode Included
- Undervoltage Lockout for High-Side and Low-Side Drivers
- Delay Matching Maxmimum of 5ns
- Propagation Delay Typical of 20ns
- Logic Input (HIN, LIN and EN) 3.3V Capability
- Ultra Low Standby Currents (<1µA)
- Extended Temperature Range: -40°C to +125°C
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DGD05473FNQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: U-DFN3030-10
- Case Material: Molded Plastic. "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—NiPdAu.
 Solderable per MIL-STD-202, Method 208@4
- Weight: 0.017 grams (Approximate)



Ordering Information (Note 4)

Ī	Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
	DGD05473FNQ-7	Automotive	DGD05473	7	8	3000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

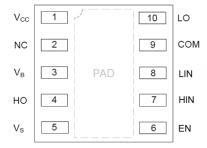
Marking Information



DGD05473 = Product Type Marking Code YY = Year (ex: 21 = 2021) WW = Week (01 to 53)



Pin Assignments

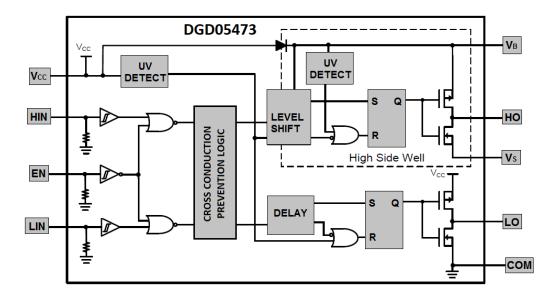


Top View: U-DFN3030-10

Pin Descriptions

Pin Number	Pin Name	Function	
1	Vcc	Low-Side and Logic Supply	
2	NC	No connection (No Internal Connection)	
3	V _B	High-Side Floating Supply	
4	НО	High-Side Gate Drive Output	
5	Vs	High-Side Floating Supply Return	
6	EN	Logic Input Enable, a Logic Low turns off Gate Driver	
7	HIN	Logic Input for High-Side Gate Driver, in Phase with HO	
8	LIN	Logic Input for Low-Side Gate Driver, in Phase with LO	
9	COM	Low-Side and Logic Return	
10	LO	Low-Side Gate Drive Output	
PAD	Substrate	Connect to COM on PCB	

Functional Block Diagram





Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
High-Side Floating Positive Supply Voltage	V _B	-0.3 to +60	V
High-Side Floating Negative Supply Voltage	Vs	V _B -14 to V _B +0.3	V
High-Side Floating Output Voltage	Vно	Vs-0.3 to V _B +0.3	V
Offset Supply Voltage Transient	dVs / dt	50	V/ns
Logic and Low-Side Fixed Supply Voltage	Vcc	-0.3 to +14	V
Low-Side Output Voltage	VLO	-0.3 to Vcc+0.3	V
Logic Input Voltage (HIN, LIN and EN)	Vin	-0.3 to Vcc+0.3	V
Bootstrap Diode Current (Pulsed <10µs)	I _{BD}	1	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation Linear Derating Factor (Note 5)	PD	0.4	W
Thermal Resistance, Junction to Ambient (Note 5)	Reja	64	°C/W
Thermal Resistance, Junction to Case (Note 5)	Rejc	42	°C/W
Operating Temperature	TJ	+150	
Lead Temperature (Soldering, 10s)	TL	+300	°C
Storage Temperature Range	Tstg	-55 to +150	

Note: 5. When mounted on a standard JEDEC 2-layer FR-4 board.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-Side Floating Supply	V _B	V _S + 4.4	V _S + 14	V
High-Side Floating Supply Offset Voltage	Vs	(Note 6)	50 (Note 7)	V
High-Side Floating Output Voltage	Vно	Vs	V _B	V
Logic and Low Side Fixed Supply Voltage	Vcc	4.7 (Note 8)	14	V
Low-Side Output Voltage	VLO	0	Vcc	V
Logic Input Voltage (HIN, LIN and EN)	Vin	0	5	V
Ambient Temperature	TA	-40	+125	°C

Notes:

- 6. Logic operation for V_S of -5V to +50V.
- 7. Provided V_B doesn't exceed absolute maximum rating of 60V.
- 8. For operation of V_{CC} = 4.7V to 4.9V, an external bootstrap Schottky diode (0.3V Vfd, 1A) is necessary, see Figure 4. For operation V_{CC} ≥ 4.9V, the external Schottky diode is not required.



DC Electrical Characteristics (V_{CC} = V_{BS} = 12V, COM = V_S = 0V, @T_A = +25°C, unless otherwise specified.) (Note 9)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Logic "1" Input Voltage	ViH	2.4	_	_	V	_
Logic "0" Input Voltage	VIL	_	_	0.8	V	_
Enable Logic "1" Input Voltage	VENIH	1.6	_	_	V	_
Enable Logic "0" Input Voltage	VENIL	_	_	0.7	V	_
Input Voltage Hysteresis	VINHYS	_	0.6	_	V	_
Enable Input Voltage Hysteresis	VENINHYS	_	0.1	_	V	_
High Level Output Voltage, VBIAS - VO	Voн	_	0.45	0.6	V	$I_{O+} = 100 \text{mA}$
Low Level Output Voltage, Vo	V_{OL}	_	0.15	0.22	V	$I_{O-} = 100 \text{mA}$
Offset Supply Leakage Current	ILK	_	1	5	μΑ	$V_B = V_S = 60V$
Vcc Shutdown Supply Current	Iccsd	_	0	1	μA	$V_{IN} = 0V$ or $5V$, $V_{EN} = 0V$
Vcc Quiescent Supply Current	Iccq	_	130	200	μΑ	$V_{IN} = 0V \text{ or } 5V$
Vcc Operating Supply Current	Іссор	_	7.3	_	mA	$fs = 500kHz, C_L = 1000pF$
V _{BS} Quiescent Supply Current	I _{BSQ}	_	40	100	μA	V _{IN} = 0V or 5V
V _{BS} Operating Supply Current	IBSOP	_	7.3	_	mA	$fs = 500kHz$. $C_L = 1000pF$
Logic "1" Input Bias Current	I _{IN+}	_	_	50	μA	$V_{IN} = 5V$
Logic "0" Input Bias Current	I _{IN} -	_	_	5	μA	$V_{IN} = 0V$
Enable Logic "1" Input Bias Current	I _{ENIN+}	_	43	60	μΑ	$V_{IN} = 5V$
Enable Logic "0" Input Bias Current	I _{ENIN} -	_	0	5	μA	$V_{IN} = 0V$
V _{BS} Supply Undervoltage Positive Going Threshold	V _{BSUV+}	3.3	3.8	4.4	V	_
V _{BS} Supply Undervoltage Negative Going Threshold	V _{BSUV} -	2.9	3.3	3.9	V	_
Vcc Supply Undervoltage Positive Going Threshold	Vccuv+	3.3	3.8	4.4	V	_
Vcc Supply Undervoltage Negative Going Threshold	Vccuv-	2.9	3.3	3.9	V	_
Output High Short Circuit Pulsed Current	I _{O+}	1.0	1.5	_	Α	V _O = 0V, PW ≤ 10μs
Output Low Short Circuit Pulsed Current	lo-	1.9	2.5	_	Α	V _O = 15V, PW ≤ 10µs
Forward Voltage of Bootstrap Diode	V _{F1}	_	0.67	_	V	$I_F = 100\mu A$
Forward Voltage of Bootstrap Diode	V _{F2}	_	1.2	_	V	I _F = 100mA

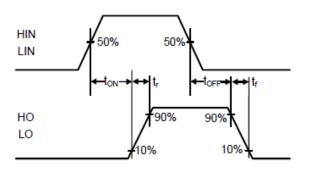
Note: 9. The V_{IN} and I_{IN} parameters are applicable to the logic pins: HIN, LIN and EN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO.

AC Electrical Characteristics (Vcc = VBS = 12V, COM = VS = 0V, CL = 1000pF, @TA = +25°C, unless otherwise specified.)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions
Turn-On Propagation Delay	ton	_	20	35	ns	_
Turn-Off Propagation Delay	toff	_	23	56	ns	Vs = 50V
Delay Matching, HO & LO Turn-On	tом	_	_	5	ns	_
Turn-On Rise Time	tr	_	16	30	ns	_
Turn-Off Fall Time	t _f	_	12	25	ns	_



Timing Waveforms



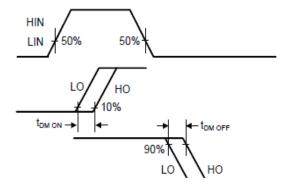


Figure 1. Switching Time Waveform Definitions

Figure 2. Delay Matching Waveform Definitions

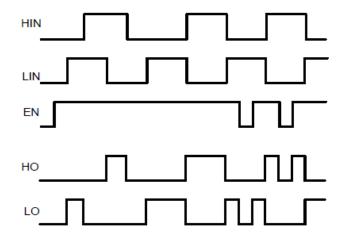


Figure 3. Input / Output Timing Diagram

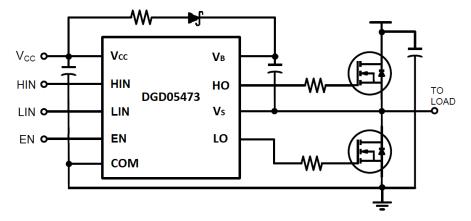


Figure 4. Typical application necessary for $V_{CC}=4.7V$ to 4.9V operation. For $V_{CC}\geq4.9V$, the bootstrap Schottky diode (0.3V Voltage drop, 1A) and resistor are not required.



Typical Performance Characteristics (Vcc = 12V, @TA = +25°C, unless otherwise specified.)

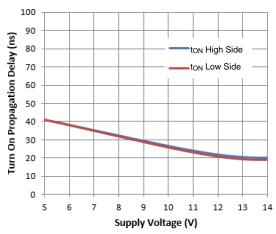


Figure 5. Turn-on Propagation Delay vs. Supply Voltage

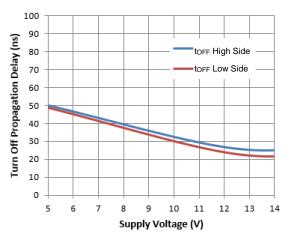


Figure 7. Turn-off Propagation Delay vs. Supply Voltage

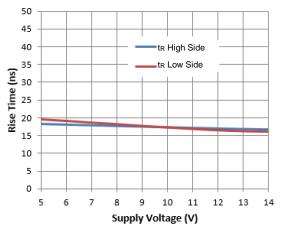


Figure 9. Rise Time vs. Supply Voltage

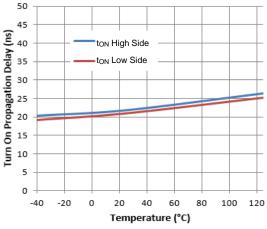


Figure 6. Turn-on Propagation Delay vs. Temperature

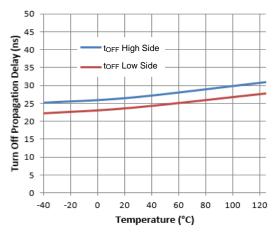


Figure 8. Turn-off Propagation Delay vs. Temperature

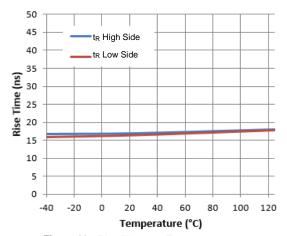


Figure 10. Rise Time vs. Temperature



Typical Performance Characteristics (continued)

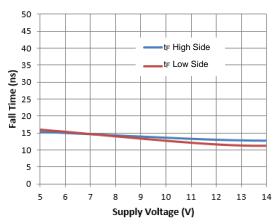


Figure 11. Fall Time vs. Supply Voltage

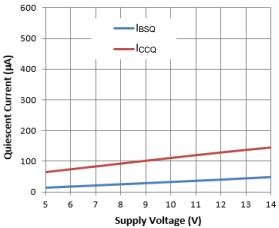


Figure 13. Quiescent Current vs. Supply Voltage

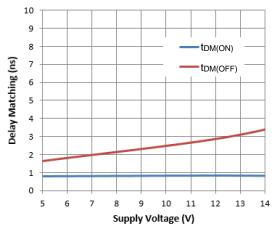


Figure 15. Delay Matching vs. Supply Voltage

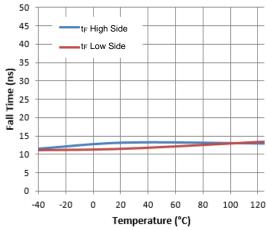


Figure 12. Fall Time vs. Temperature

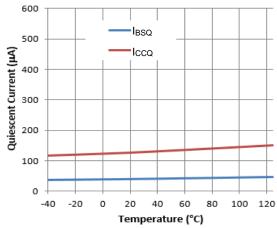


Figure 14. Quiescent Current vs. Temperature

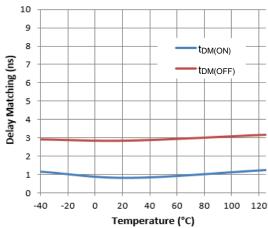


Figure 16. Delay Matching vs. Temperature



Typical Performance Characteristics (continued)

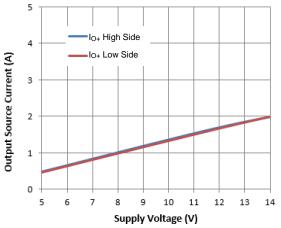


Figure 17. Output Source Current vs. Supply Voltage

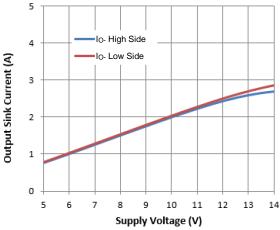


Figure 19. Output Sink Current vs. Supply Voltage

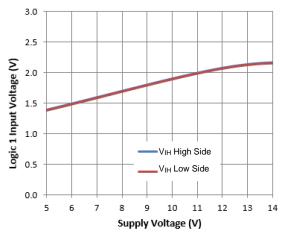


Figure 21. Logic 1 Input Voltage vs. Supply Voltage

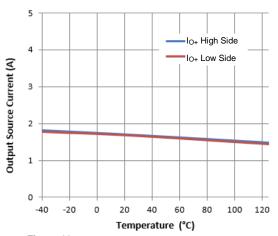


Figure 18. Output Source Current vs. Temperature

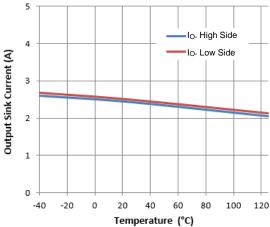


Figure 20. Output Sink Current vs. Temperature

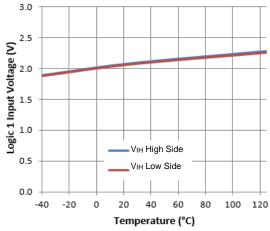


Figure 22. Logic 1 Input Voltage vs. Temperature



Typical Performance Characteristics (continued)

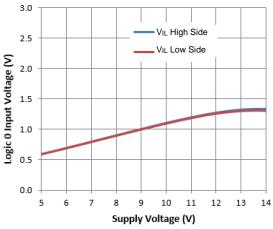


Figure 23. Logic 0 Input Voltage vs. Supply Voltage

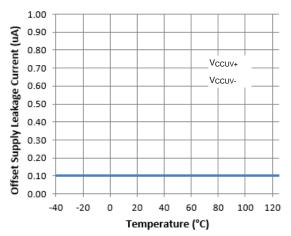


Figure 25. Offset Supply Leakage Current vs. Temperature

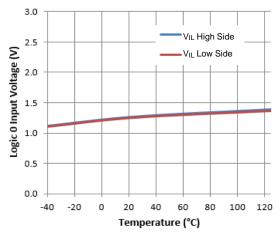


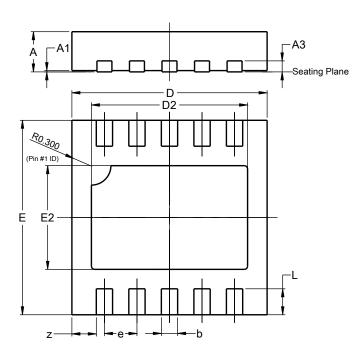
Figure 24. Logic 0 Input Voltage vs. Temperature



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

U-DFN3030-10

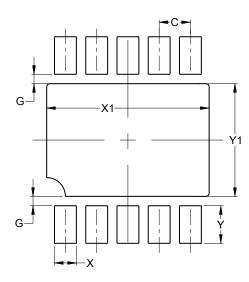


U-DFN3030-10					
Dim	Min	Max	Тур		
Α	0.57	0.63	0.60		
A1	0.00	0.05	0.02		
А3			0.15		
b	0.20	0.30	0.25		
D	2.90	3.10	3.00		
D2	2.30	2.50	2.40		
Е	2.90	3.10	3.00		
E2	1.50	1.70	1.60		
е	1		0.50		
٦	0.25	0.55	0.40		
Z	-		0.375		
All Dimensions in mm					

Suggested Pad Layout

 $\label{please} Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

U-DFN3030-10



Dimensions	Value (in mm)		
С	0.50		
G	0.15		
Х	0.35		
X1	2.60		
Y	0.60		
Y1	1.80		



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